



# SS12T THRU SS120T

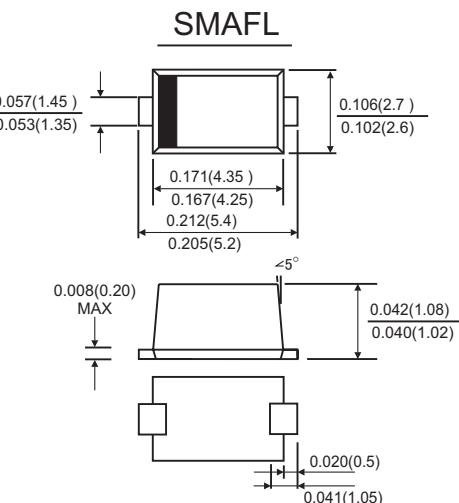
SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts

Forward Current - 1.0Ampere

## FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Ultra-thin surface mounted package
- Metal silicon junction, majority carrier conduction
- For surface mount applications
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters,
- free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 260°C/10 seconds at terminals
- Component in accordance to RoHS 2011/65/EU



Dimensions in inches and (millimeters)

## MECHANICAL DATA

- Case: SMAFL(DO-214AC) molded plastic body
- TerMINals: Solder Plated, solderable per MIL-STD-750, method 2026
- Polarity: Color band denotes cathode end

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified, Single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%.)

	Symbols	SS 12T	SS 13T	SS 14T	SS 16T	SS 110T	SS 115T	SS 120T	Volts
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	60	100	150	200	Volts
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	42	71	105	140	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	60	100	150	200	Volts
Maximum average forward rectified current (See Fig. 1)	I <sub>(AV)</sub>					1.0			Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>					40.0			Amps
Maximum instantaneous forward voltage at 1.0 A (note 1)	V <sub>F</sub>		0.55		0.75	0.85	0.90	0.95	Volts
Maximum instantaneous reverse current at rated DC blocking voltage (Note 1)	T <sub>A</sub> =25°C	I <sub>R</sub>	100			20			μA
	T = 100°C		5			-			mA
	T <sub>A</sub> =125°C		-			3			
Typical thermal resistance (Note 2)	R <sub>JA</sub> R <sub>JL</sub>				115 28.0				°C/W
Operating junction temperature range	T <sub>J</sub>				-65 to +150				°C
Storage temperature range	T <sub>STG</sub>				-65 to +150				°C

Notes: 1. Pulse test: 300μs pulse width, 1% duty cycle

2. P.C.B. mounted with 0.2 X 0.2"(5.0 X 5.0mm) copper pad areas

## RATINGS AND CHARACTERISTIC CURVES SS12T THRU SS120T

FIG.1-FORWARD CURRENT DERATING CURVE

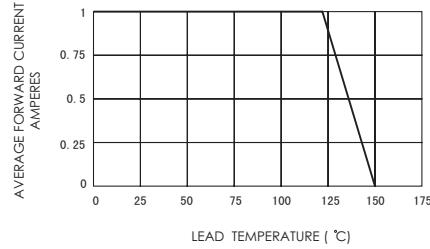


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

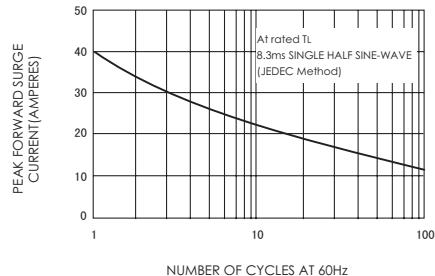


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

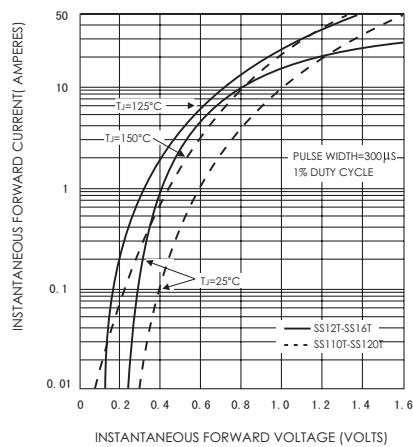


FIG.4-TYPICAL REVERSE CHARACTERISTICS

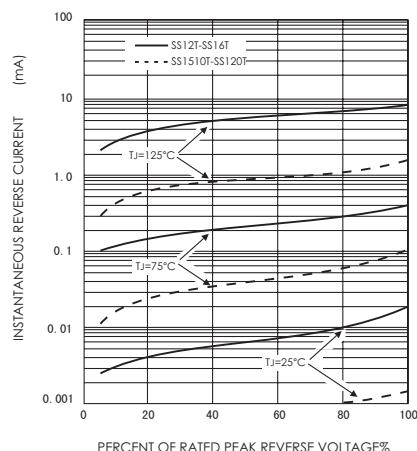


FIG.5-TYPICAL JUNCTION CAPACITANCE

